Low Voltage Comparator

The NCS2220A is an industry first sub—one volt, low power dual comparator. This device consumes only 7.5 μ A per Comparator of supply current. It is guaranteed to operate at a low voltage of 0.85 V which allows it to be used in systems that require less than 1.0 V and is fully operational up to 6.0 V which makes it convenient for use in both 3.0 V and 5.0 V systems. Additional features include no output phase inversion with overdriven inputs, internal hysteresis, which allows for clean output switching, and rail—to—rail input and output performance. The NCS2220A is available in the tiny UDFN 1.6 X 1.6 package.

Features

- Operating Voltage of 0.85 V to 6.0 V
- Rail-to-Rail Input/Output Performance
- Low Supply Current of 7.5 μA per Comparator Typ
- No Phase Inversion with Overdriven Input Signals
- Internal Hysteresis
- Propagation Delay of 0.5 μs
- This is a Pb-Free Device

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Alarm and Security Systems
- Personal Digital Assistants



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UDFN8 1.6 X 1.6 MU SUFFIX CASE 517AC



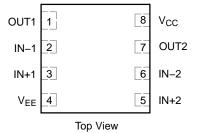
CZ = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping [†]
NCS2220AMUT1G	Complementary UDFN 1.6 X 1.6	3000/ Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range (V _{CC} to V _{EE})	V _S	6.0	V
Non-inverting/Inverting Input to V _{EE}	-	-0.2 to (V _{CC} + 0.2)	V
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature	T _A	-40 to +105	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Output Short Circuit Duration Time (Note 1)	t _S	Indefinite	S
ESD Tolerance (Note 2) NCS2220A Human Body Model Machine Model	-	2000 200	V
Thermal Resistance, Junction-to-Ambient UDFN	$R_{ hetaJA}$	350	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect Recommended Operating Conditions is not implied. Extended exposure to sidevice reliability.

1. The maximum package power dissipation limit must not be exceeded. $PD = \frac{TJ(max) - TA}{R_{\theta}JA}$ 2. ESD data available upon request.

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta,JA}}$$

 $\textbf{ELECTRICAL CHARACTERISTICS} \text{ (For all values V}_{CC} = 0.85 \text{ V to } 6.0 \text{ V}, \text{ V}_{EE} = 0 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ unless otherwise noted.)} \text{ (Note 3)}$

Characteristics	Symbol	Min	Тур	Max	Unit
Input Hysteresis T _A = 25°C	V _{HYS}	2.0	4.5	20	mV
Input Offset Voltage $V_{CC} = 0.85 \text{ V}$ $T_{A} = 25^{\circ}\text{C}$ $T_{A} = -40^{\circ}\text{C to } 105^{\circ}\text{C}$	V _{IO}	-10 -12	0.5 -	+10 +12	mV
$V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V}$		-6.0 -8.0	0.5 -	+6.0 +8.0	
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-5.0 -7.0	0.5 -	+5.0 +7.0	
Common Mode Voltage Range	V _{CM}	-	V _{EE} to V _{CC}	_	V
Output Short-Circuit Sourcing or Sinking	I _{SC}	-	60	_	mA
Common Mode Rejection Ratio V _{CM} = V _{CC}	CMRR	53	70	_	dB
Input Bias Current	I _{IB}	-	1.0	-	рА
Power Supply Rejection Ratio $\Delta V_S = 2.575 \text{ V}$	PSRR	45	80	_	dB
Supply Current per Comparator $V_{CC} = 0.85 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to 105°C	Icc	-	7.5 -	15 17	μΑ
$V_{CC} = 3.0 \text{ V}$ $T_{A} = 25^{\circ}\text{C}$ $T_{A} = -40^{\circ}\text{C}$ to 105°C $V_{CC} = 6.0 \text{ V}$		_	8.0 –	15 17	
$T_A = 25$ °C $T_A = -40$ °C to 105°C		_	9.0 -	15 17	
Output Voltage High $ \begin{array}{l} \text{V}_{CC} = 0.85 \text{ V}, I_{source} = 0.5 \text{ mA} \\ \text{T}_{A} = 25^{\circ}\text{C} \\ \text{T}_{A} = -40^{\circ}\text{C to } 105^{\circ}\text{C} \\ \text{V}_{CC} = 3.0 \text{ V}, I_{source} = 3.0 \text{ mA} \\ \text{T}_{A} = 25^{\circ}\text{C} \end{array} $	V _{OH}	V _{CC} - 0.25 V _{CC} - 0.275 V _{CC} - 0.3	V _{CC} - 0.12 - V _{CC} - 0.12	-	V
$T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V, } I_{\text{source}} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C to } 105^{\circ}\text{C}$		V _{CC} - 0.35 V _{CC} - 0.3 V _{CC} - 0.35	V _{CC} - 0.17	-	
Output Voltage Low $V_{CC} = 0.85 \text{ V, } I_{sink} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C to } 105^{\circ}\text{C}$ $V_{CC} = 3.0 \text{ V, } I_{sink} = 3.0 \text{ mA}$	V _{OL}	-	V _{EE} + 0.10	V _{EE} + 0.25 V _{EE} + 0.275	V
$T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to 105°C $V_{CC} = 6.0 \text{ V}$, $I_{sink} = 5.0 \text{ mA}$		-	V _{EE} + 0.12 -	V _{EE} + 0.3 V _{EE} + 0.35	
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-	V _{EE} + 0.12 -	V _{EE} + 0.3 V _{EE} + 0.35	
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	^t PHL ^t PLH	- -	0.5 0.5	- -	μs
Output Fall Time $V_{CC} = 6.0 \text{ V}$, $C_L = 50 \text{ pF}$ (Note 4)	t _{FALL}	-	20	-	ns
Output Rise Time $V_{CC} = 6.0 \text{ V}$, $C_L = 50 \text{ pF (Note 4)}$	t _{RISE}	-	16	-	ns

^{3.} The limits over the extended temperature range are guaranteed by design only.4. Input signal: 1 kHz, squarewave signal with 10 ns edge rate.

1000

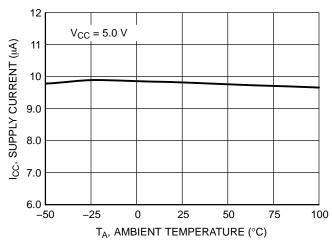
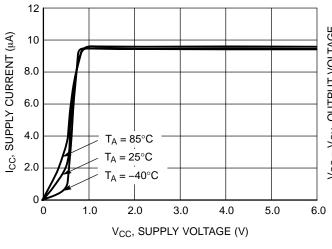


Figure 1. NCS2220A Supply Current versus Temperature/Comparator

Figure 2. NCS2220A Supply Current versus Output Transition Frequency/Comparator



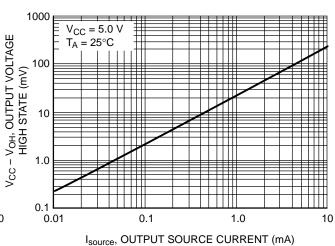
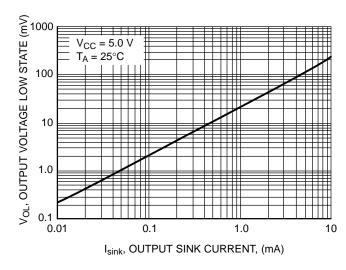


Figure 3. NCS2220A Supply Current versus Supply Voltage/Comparator

Figure 4. NCS2220A Output Voltage High State versus Output Source Current



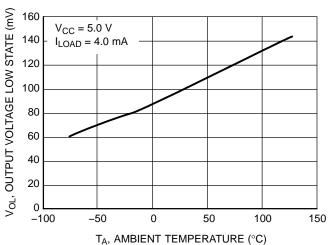


Figure 5. NCS2220A Output Voltage Low State versus Output Sink Current

Figure 6. NCS2220A Output Voltage Low State versus Temperature

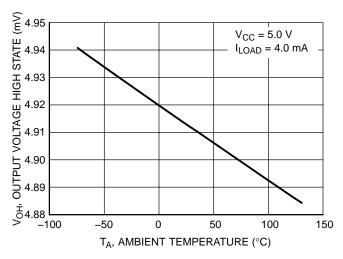


Figure 7. NCS2220A Output Voltage High State versus Temperature

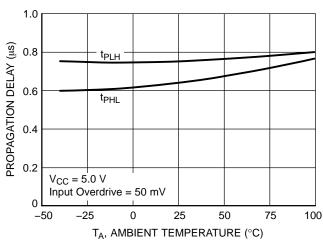


Figure 8. NCS2220A Propagation Delay versus Temperature

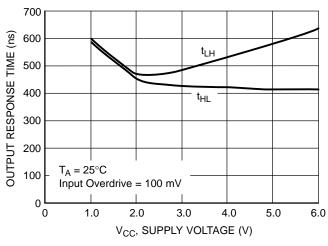


Figure 9. NCS2220A Output Response Time versus Supply Voltage

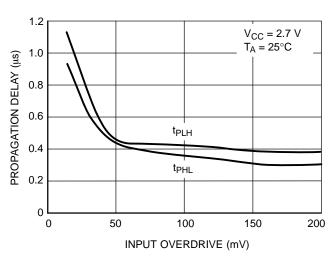


Figure 10. NCS2220A Propagation Delay versus Input Overdrive

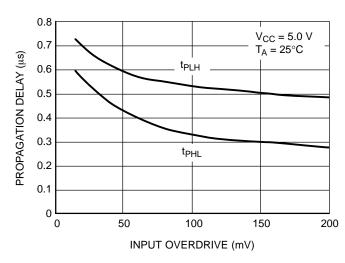


Figure 11. NCS2220A Propagation Delay versus Input Overdrive

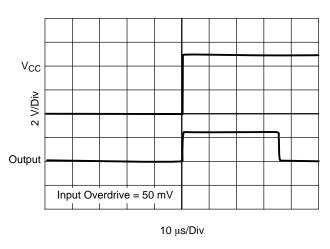


Figure 12. NCS2220A Powerup Delay

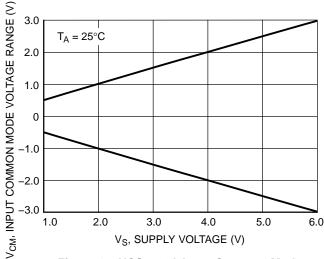


Figure 13. NCS2220A Input Common Mode Voltage Range versus Supply Voltage

OPERATING DESCRIPTION

The NCS2220A is an industry first sub–one volt, low power comparator. This device is designed for rail–to–rail input and output performance. This device consumes only $10~\mu\text{A/C}$ omparator of supply current while achieving a typical propagation delay of 1.1 μs at a 20 mV input overdrive. Figures 10 and 11 show propagation delay with various input overdrives. This comparator is guaranteed to operate at a low voltage of 0.85 V up to 6.0 V. This is accomplished by the use of a modified analog CMOS process that implements depletion MOSFET devices. The common–mode input voltage range extends 0.1 V beyond

the upper and lower rail without phase inversion or other adverse effects. This device has a typical internal hysteresis of ± 8.0 mV. This allows for greater noise immunity and clean output switching.

Output Stage

The NCS2220A has a complementary P and N Channel output stage that has capability of driving a rail-to-rail output swing with a load ranging up to 5.0 mA. It is designed such that shoot-through current is minimized while switching. This feature eliminates the need for bypass capacitors under most circumstances.

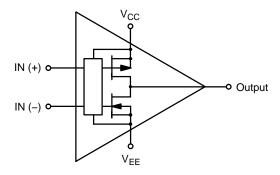
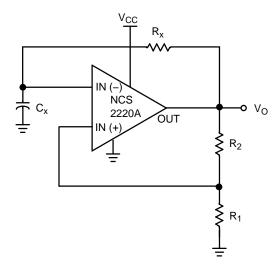


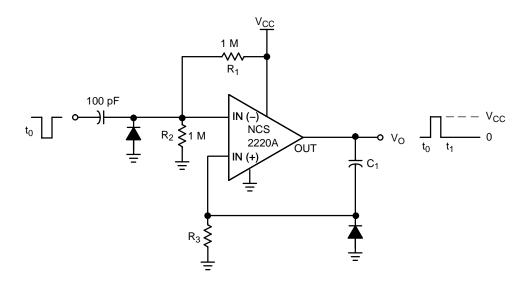
Figure 14. NCS2220A Complementary Output Configuration



The oscillation frequency can be programmed as follows:

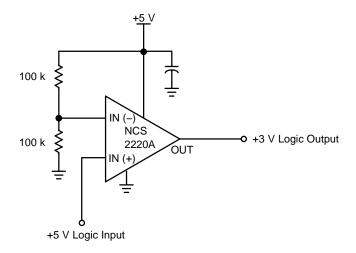
$$f = \frac{1}{T} = \frac{1}{2.2 \; R_X C_X}$$

Figure 15. Schmitt Trigger Oscillator



The resistor divider R_1 and R_2 can be used to set the magnitude of the input pulse. The pulse width is set by adjusting C_1 and R_3 .

Figure 16. One-Shot Multivibrator



This circuit converts 5 V logic to 3 V logic. Using the NCS2220A allows for full 5 V logic swing without creating overvoltage on the 3 V logic input.

Figure 17. Logic Level Translator

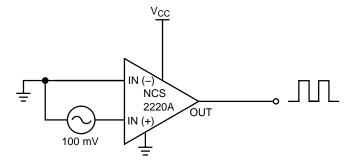
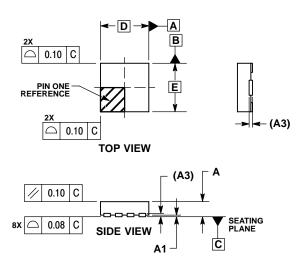


Figure 18. Zero-Crossing Detector

PACKAGE DIMENSIONS

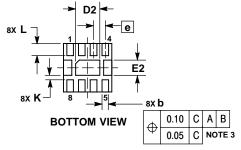
UDFN8, 1.6x1.6, 0.4P CASE 517AC-01 ISSUE A

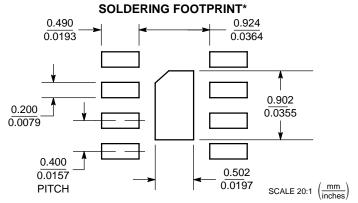


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION 6 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.
- U.3J mm FROM TERMINAL.
 COPLANARITY APPLIES TO THE EXPOSED
 PAD AS WELL AS THE TERMINALS.
 EXPOSED PADS CONNECTED TO DIE FLAG.
 USED AS TEST CONTACTS.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.45	0.50	0.55		
A1	0.00	0.03	0.05		
A3	0.127 REF				
b	0.15	0.20	0.25		
D	1.60 BSC				
D2	0.70	0.90			
E		1.60 BSC			
E2	0.40	0.50	0.60		
е	0.40 BSC				
K	0.20				
L	0.20	0.30	0.40		





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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